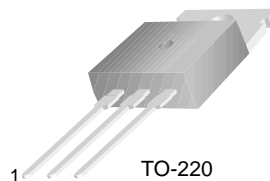


## KSE13006/13007

### High Voltage Switch Mode Application

- High Speed Switching
- Suitable for Switching Regulator and Motor Control



TO-220  
1.Base 2.Collector 3.Emitter

### NPN Silicon Transistor

#### Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

| Symbol    | Parameter  | Value      | Units            |
|-----------|--|------------|------------------|
| $V_{CBO}$ | Collector-Base Voltage                           | : KSE13006 | 600              |
|           |  | : KSE13007 | 700              |
| $V_{CEO}$ | Collector-Emitter Voltage                        | : KSE13006 | 300              |
|           |  | : KSE13007 | 400              |
| $V_{EBO}$ | Emitter- Base Voltage                            | 9          | V                |
| $I_C$     | Collector Current (DC)                           | 8          | A                |
| $I_{CP}$  | Collector Current (Pulse)                        | 16         | A                |
| $I_B$     | Base Current                                     | 4          | A                |
| $P_C$     | Collector Dissipation ( $T_C=25^\circ\text{C}$ ) | 80         | W                |
| $T_J$     | Junction Temperature                             | 150        | $^\circ\text{C}$ |
| $T_{STG}$ | Storage Temperature                              | - 65 ~ 150 | $^\circ\text{C}$ |

#### Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

| Symbol        | Parameter  | Test Condition  | Min. | Typ. | Max. | Units         |
|---------------|--|---|------|------|------|---------------|
| $BV_{CEO}$    | Collector- Emitter Breakdown Voltage<br>: KSE13006<br>: KSE13007 | $I_C = 10\text{mA}, I_B = 0$  | 300  |      |      | V             |
|               |  |   | 400  |      |      | V             |
| $I_{EBO}$     | Emitter Cut-off Current  | $V_{EB} = 9\text{V}, I_C = 0$   |      |      | 1    | mA            |
| $h_{FE}$      | *DC Current Gain   | $V_{CE} = 5\text{V}, I_C = 2\text{A}$   | 8    |      | 60   |               |
|               |  | $V_{CE} = 5\text{V}, I_C = 5\text{A}$   | 5    |      | 30   |               |
| $V_{CE(sat)}$ | *Collector-Emitter Saturation Voltage                            | $I_C = 2\text{A}, I_B = 0.4\text{A}$  |      |      | 1    | V             |
|               |  | $I_C = 5\text{A}, I_B = 1\text{A}$  |      |      | 2    | V             |
|               |  | $I_C = 8\text{A}, I_B = 2\text{A}$  |      |      | 3    | V             |
| $V_{BE(sat)}$ | *Base-Emitter Saturation Voltage                                 | $I_C = 2\text{A}, I_B = 0.4\text{A}$  |      |      | 1.2  | V             |
|               |  | $I_C = 5\text{A}, I_B = 1\text{A}$  |      |      | 1.6  | V             |
| $C_{ob}$      | Output Capacitance   | $V_{CB} = 10\text{V}, f = 0.1\text{MHz}$  |      | 110  |      | pF            |
| $f_T$         | Current Gain Bandwidth Product                                   | $V_{CE} = 10\text{V}, I_C = 0.5\text{A}$  | 4    |      |      | MHz           |
| $t_{ON}$      | Turn On Time   | $V_{CC} = 125\text{V}, I_C = 5\text{A}$<br>$I_{B1} = -I_{B2} = 1\text{A}$<br>$R_L = 50\Omega$ |      |      | 1.6  | $\mu\text{s}$ |
| $t_{STG}$     | Storage Time   |   |      |      | 3    | $\mu\text{s}$ |
| $t_F$         | Fall Time  |   |      |      | 0.7  | $\mu\text{s}$ |

\* Pulse test:  $PW \leq 300\mu\text{s}$ , Duty cycle  $\leq 2\%$

# Typical Characteristics

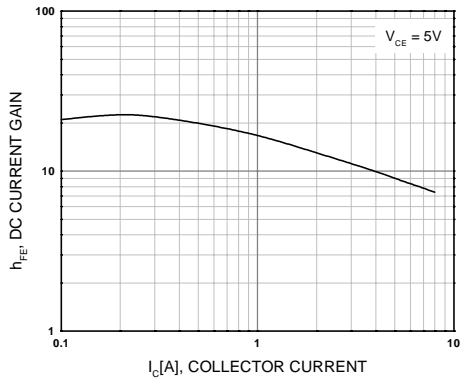


Figure 1. DC current Gain

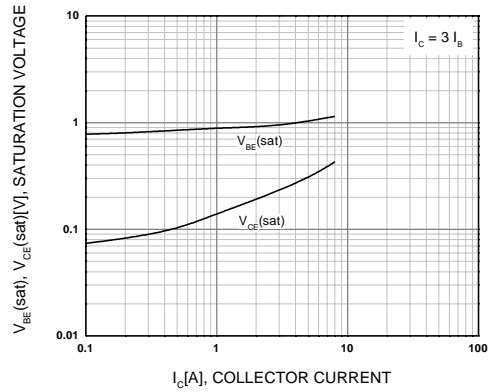


Figure 2. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage

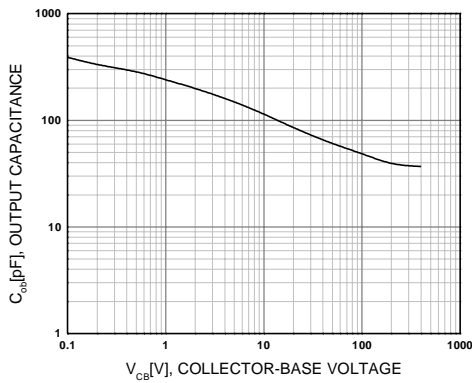


Figure 3. Collector Output Capacitance

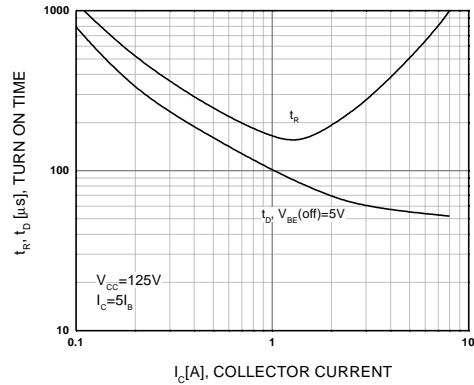


Figure 4. Turn On Time

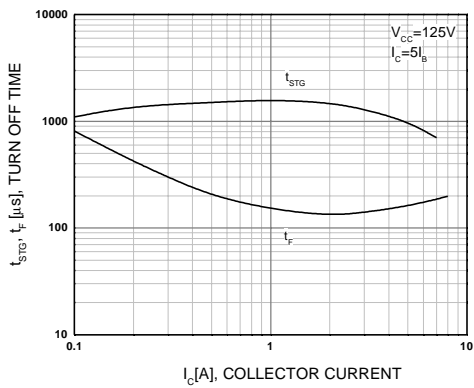


Figure 5. Turn Off Time

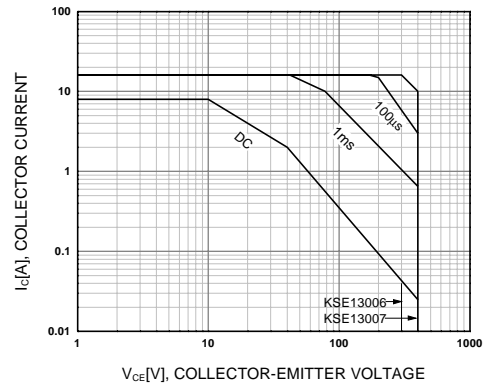


Figure 6. Safe Operating Area

# Typical Characteristics (Continued)

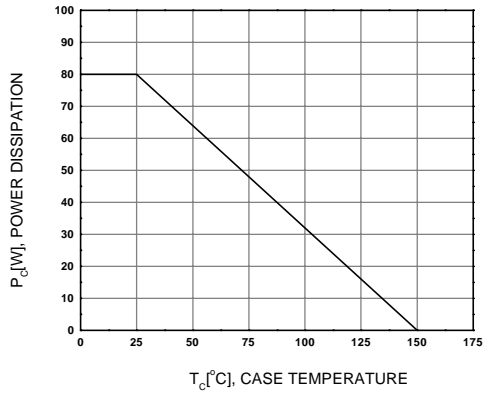
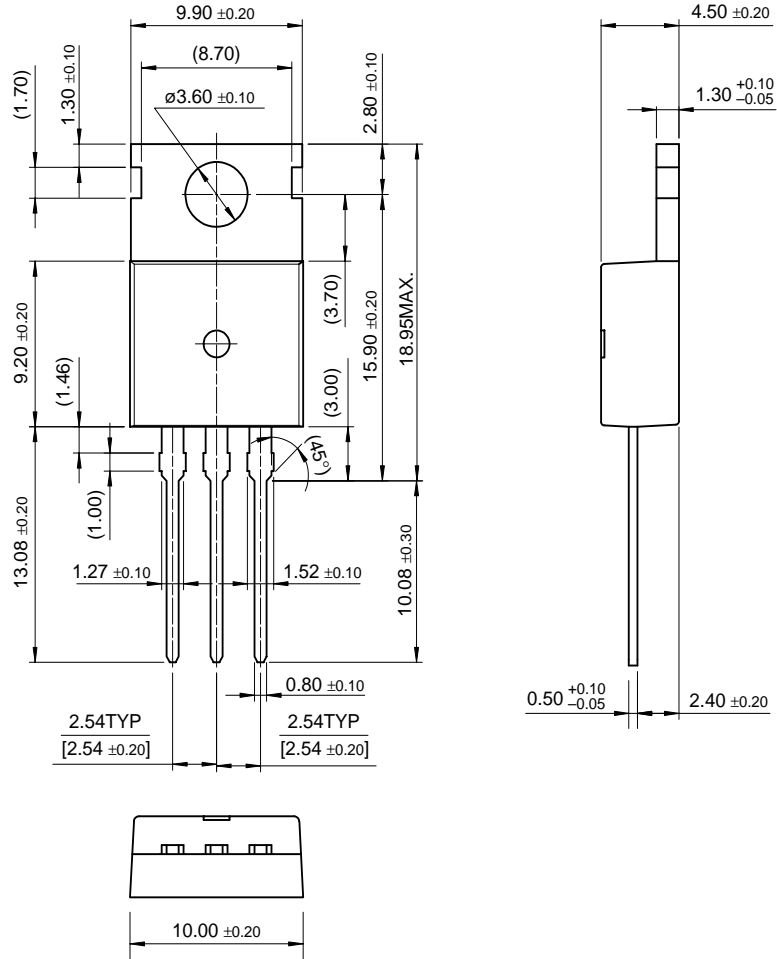


Figure 7. Power Derating

# Package Dimensions

## TO-220

KSE13006/13007



Dimensions in Millimeters

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|----------------------|---------------|-------------|
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| CROSSVOLT™           | POP™          | UHC™        |
| E <sup>2</sup> CMOS™ | PowerTrench®  | VCX™        |
| FACT™                | QFET™         |             |
| FACT Quiet Series™   | QS™           |             |
| FAST®                | Quiet Series™ |             |
| FASTr™               | SuperSOT™-3   |             |
| GTO™                 | SuperSOT™-6   |             |

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